onsemi

NPN High-Power Transistors

TIP33C

Designed for general-purpose power amplifier and switching applications.

Features

- ESD Ratings: Machine Model, C; > 400 V Human Body Model, 3B; > 8000 V
- Epoxy Meets UL 94 V-0 @ 0.125 in
- These Devices is Pb-Free*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	100	Vdc
Collector – Base Voltage	V _{CBO}	100	Vdc
Emitter – Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous – Peak (Note 1)	Ι _C	10 15	Adc Apk
Base Current – Continuous	Ι _Β	3.0	Adc
Total Device Dissipation @ $T_C = 25^{\circ}C$ Derate above $25^{\circ}C$	PD	80 0.64	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	−65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit	
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.56	°C/W	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	35.7	°C/W	

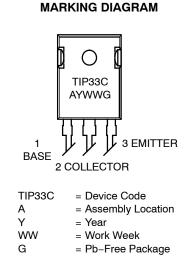
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.



TO-247 CASE 340L STYLE 3

10 AMPERE NPN SILICON POWER TRANSISTORS 60 & 100 VOLT, 80 WATTS



ORDERING INFORMATION

Device	Package	Shipping [†]
TIP33CG	TO–247 (Pb–Free)	30 Units / Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

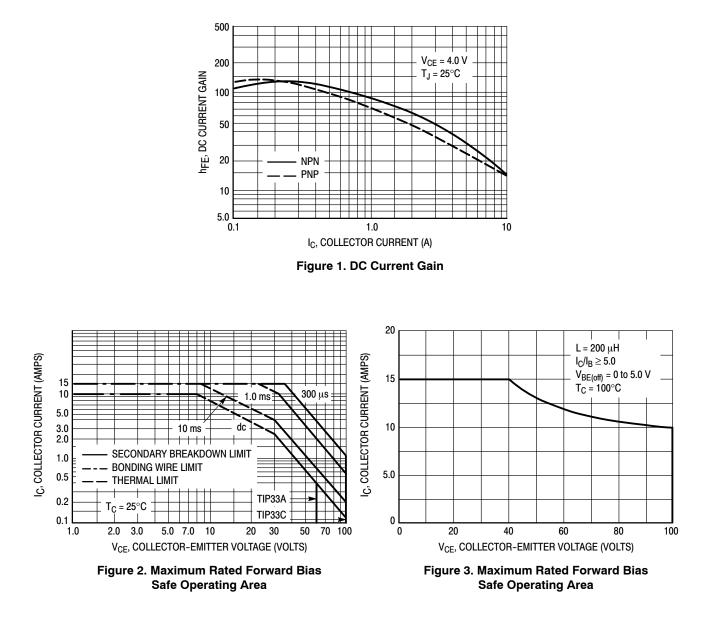
TIP33C

ELECTRICAL CHARACTERISTICS (T_C = 25 $^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	
Collector-Emitter Sustaining Voltage (Note 2) (I_C = 30 mA, I_B = 0)	V _{CEO(sus)}	100		Vdc
Collector–Emitter Cutoff Current (V _{CE} = 30 V, $I_B = 0$) (V _{CE} = 60 V, $I_B = 0$)	I _{CEO}	_	0.7	mA
Collector–Emitter Cutoff Current $(V_{CE} = Rated V_{CEO}, V_{EB} = 0)$	I _{CES}	_	0.4	mA
Emitter-Base Cutoff Current ($V_{EB} = 5.0 \text{ V}, I_C = 0$)	I _{EBO}	_	1.0	mA
ON CHARACTERISTICS (Note 2)				
DC Current Gain (I _C = 1.0 A, V _{CE} = 4.0 V) (I _C = 3.0 A, V _{CE} = 4.0 V)	h _{FE}	40 20	_ 100	-
Collector–Emitter Saturation Voltage ($I_C = 3.0 \text{ A}, I_B = 0.3 \text{ A}$) ($I_C = 10 \text{ A}, I_B = 2.5 \text{ A}$)	V _{CE(sat)}		1.0 4.0	Vdc
Base-Emitter On Voltage ($I_C = 3.0 \text{ A}, V_{CE} = 4.0 \text{ V}$) ($I_C = 10 \text{ A}, V_{CE} = 4.0 \text{ V}$)	V _{BE(on)}		1.6 3.0	Vdc
DYNAMIC CHARACTERISTICS				
Small–Signal Current Gain ($I_C = 0.5 \text{ A}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$)	h _{fe}	20	_	-
Current–Gain — Bandwidth Product (I _C = 0.5 A, V _{CE} = 10 V, f = 1.0 MHz)	f _T	3.0	-	MHz

2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

TIP33C



FORWARD BIAS

The Forward Bias Safe Operating Area represents the voltage and current conditions these devices can withstand during forward bias. The data is based on $T_C = 25^{\circ}C$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10%, and must be derated thermally for $T_C > 25^{\circ}C$.

REVERSE BIAS

The Reverse Bias Safe Operating Area represents the voltage and current conditions these devices can withstand during reverse biased turn–off. This rating is verified under clamped conditions so the device is never subjected to an avalanche mode.

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TO-247 CASE 340L ISSUE G G SCALE 1:1 Т В EATING -Ν Α 7 . ർറ ∲Ø0.63 (0.025)@|T|B@ Р Ý 2X F G ·H ЗХ D ♦ 0.25 (0.010) W Y AS

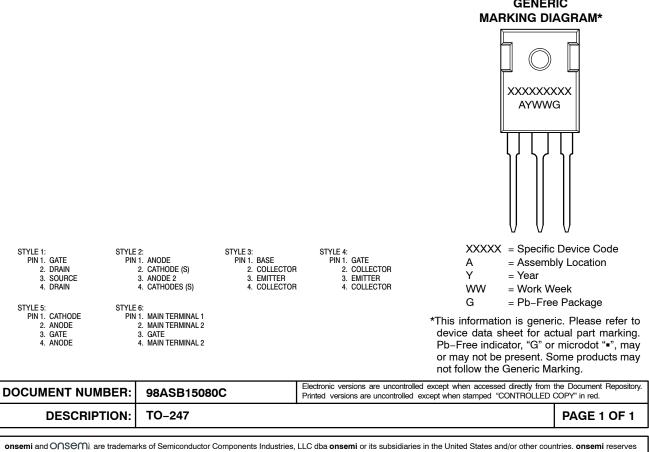
DATE 06 OCT 2021

NOTES

- DIMENSIONING AND TOLERANCING PER ASME 1. Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER

	MILLIMETERS		INC	HES
DIM	MIN.	MAX.	MIN.	MAX.
A	20.32	21.08	0.800	0.830
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
н	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
к	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
Р		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

GENERIC



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